Product data sheet

1. General description

The 74LVC1G00 provides the single 2-input NAND function.

Input can be driven from either 3.3 V or 5 V devices. These features allow the use of these devices in a mixed 3.3 V and 5 V environment.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- ± 24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



3. Ordering information

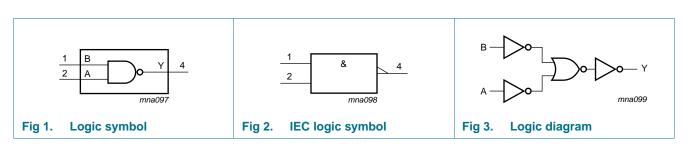
Table 1. Ordering	information			
Type number	Package			
	Temperature range	Name	Description	Version
74LVC1G00GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74LVC1G00GV	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753
74LVC1G00GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm	SOT886
74LVC1G00GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm	SOT891
74LVC1G00GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9\times1.0\times0.35$ mm	SOT1115
74LVC1G00GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 \times 1.0 \times 0.35 mm	SOT1202
74LVC1G00GX	–40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226

4. Marking

Type number	Marking ^[1]
74LVC1G00GW	VA
74LVC1G00GV	V00
74LVC1G00GM	VA
74LVC1G00GF	VA
74LVC1G00GN	VA
74LVC1G00GS	VA
74LVC1G00GX	VA

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

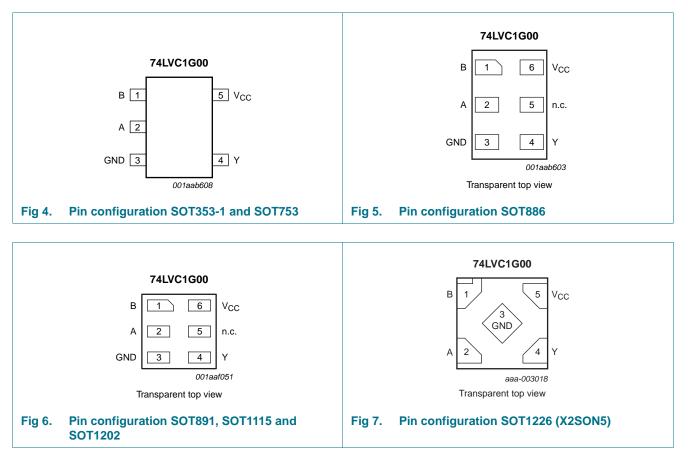
5. Functional diagram



74LVC1G00 Product data sheet

6. Pinning information

6.1 Pinning



6.2 Pin description

B 1 A 2	Table 3. Pin description							
B 1 A 2	in		Description					
A 2	SSOP5 and X2SON5	XSON6						
		1	data input					
		2	data input					
GND 3		3	ground (0 V)					
Y 4		4	data output					
n.c		5	not connected					
V _{CC} 5		6	supply voltage					

7. Functional description

Table 4.	Function table ^[1]		
Inputs			Outputs
Α		В	Y
L		L	н
L		Н	Н
Н		L	Н
Н		Н	L
-			

[1] H = HIGH voltage level; L = LOW voltage level.

Limiting values 8.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V	-	±50	mA
Vo	output voltage	Active mode	[1][2] -0.5	$V_{CC} + 0.5$	V
		Power-down mode	[1][2] -0.5	+6.5	V
I _O	output current	$V_{O} = 0 V$ to V_{CC}	-	±50	mA
I _{CC}	supply current		-	+100	mA
I _{GND}	ground current		-100	-	mA
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3]	250	mW
T _{stg}	storage temperature		-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When $V_{CC} = 0 V$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

For TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K. [3] For XSON6 and X2SON5 packages: above 118 $^\circ\text{C}$ the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6.	Recommended operating conditions						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V _{CC}	supply voltage		1.65	-	5.5	V	
VI	input voltage		0	-	5.5	V	
V _O output volta	output voltage	Active mode	0	-	V _{CC}	V	
		$V_{CC} = 0 V$; Power-down mode	0	-	5.5	V	
T _{amb}	ambient temperature		-40	-	+125	°C	
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	-	-	20	ns/V	
		$V_{CC} = 2.7 \text{ V} \text{ to } 5.5 \text{ V}$	-	-	10	ns/V	

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	Unit	
		Min	Typ[1]	Max	Min	Max		
VIH	HIGH-level	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	$0.65V_{CC}$	-	-	$0.65V_{CC}$	-	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		V_{CC} = 4.5 V to 5.5 V	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	V
VIL	LOW-level	V_{CC} = 1.65 V to 1.95 V	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
		V_{CC} = 4.5 V to 5.5 V	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	$I_{O} = -100 \ \mu A;$ $V_{CC} = 1.65 \ V \ to \ 5.5 \ V$	V _{CC} - 0.1	-	-	$V_{CC}-0.1$	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	0.95	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	1.7	-	V
		I_{O} = -12 mA; V_{CC} = 2.7 V	2.2	-	-	1.9	-	V
		$I_0 = -24$ mA; $V_{CC} = 3.0$ V	2.3	-	-	2.0	-	V
		$I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	3.4	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.45	-	0.70	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.3	-	0.45	V
		$I_0 = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	-	0.60	V
		$I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.80	V
		$I_{O} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.55	-	0.80	V
lı	input leakage current	$V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	±0.1	±5	-	±100	μΑ

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).									
Symbol Parameter Conditions	Parameter	Conditions	–40 °C to +85 °C			–40 °C to	+125 °C	Unit	
	Min	Typ[1]	Мах	Min	Мах				
I _{OFF}	power-off leakage current	$V_{CC} = 0$ V; V _I or V _O = 5.5 V	-	±0.1	±10	-	±200	μA	
I _{CC}	supply current	$V_{I} = 5.5 V \text{ or GND}; I_{O} = 0 A;$ $V_{CC} = 1.65 V \text{ to } 5.5 V$	-	0.1	10	-	200	μA	
ΔI_{CC}	additional supply current		-	5	500	-	5000	μΑ	
Cı	input capacitance	V_{CC} = 3.3 V; V_{I} = GND to V_{CC}	-	5	-	-	-	pF	

Table 7. Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8.Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see <u>Figure 9</u>.

Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C to +125 °C		Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t _{pd}	propagation delay	A, B to Y; see Figure 8	[2]						
		V_{CC} = 1.65 V to 1.95 V		1.0	3.3	8.0	1.0	10.5	ns
		V_{CC} = 2.3 V to 2.7 V		0.5	2.2	5.5	0.5	7.0	ns
		$V_{CC} = 2.7 V$		0.5	2.6	5.8	0.5	7.5	ns
		V_{CC} = 3.0 V to 3.6 V		0.5	2.2	4.7	0.5	6.0	ns
		V_{CC} = 4.5 V to 5.5 V		0.5	1.8	4.0	0.5	5.5	ns
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ $V_{CC} = 3.3 \text{ V}$	[3]	-	14	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of outputs.

Single 2-input NAND gate

12. Waveforms

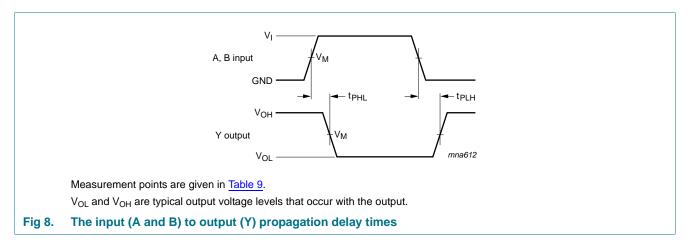


Table 9.Measurement points

Supply voltage	Input	Output
V _{cc}	V _M	V _M
1.65 V to 1.95 V	0.5V _{CC}	0.5V _{CC}
2.3 V to 2.7 V	0.5V _{CC}	0.5V _{CC}
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	0.5V _{CC}	0.5V _{CC}

Single 2-input NAND gate

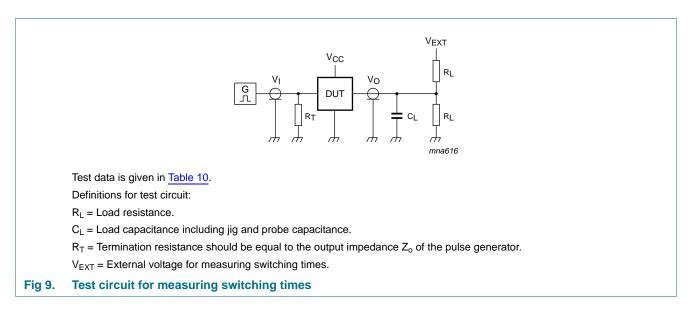


Table 10. Test data

Supply voltage	Input		Load		V _{EXT}
V _{cc}	VI	$t_r = t_f$	CL	RL	t _{PLH} , t _{PHL}
1.65 V to 1.95 V	V _{CC}	\leq 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V _{CC}	\leq 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V _{CC}	\leq 2.5 ns	50 pF	500 Ω	open

Single 2-input NAND gate

13. Package outline

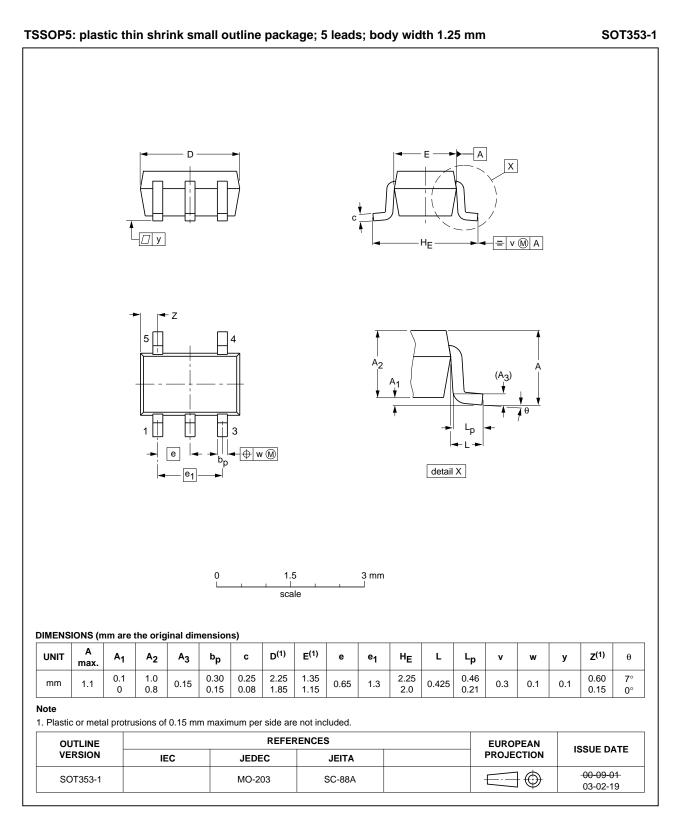
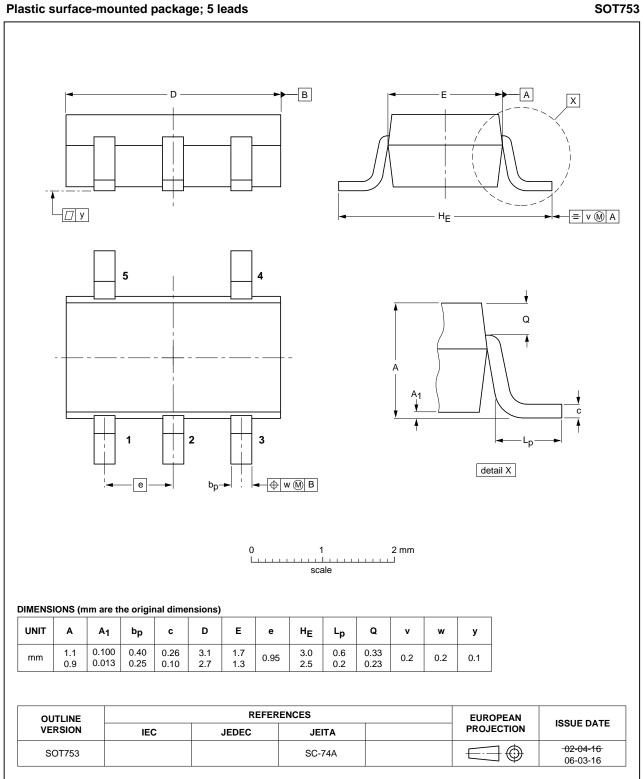


Fig 10. Package outline SOT353-1 (TSSOP5)

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Plastic surface-mounted package; 5 leads

Fig 11. Package outline SOT753 (SC-74A)

74LVC1G00

Product data sheet

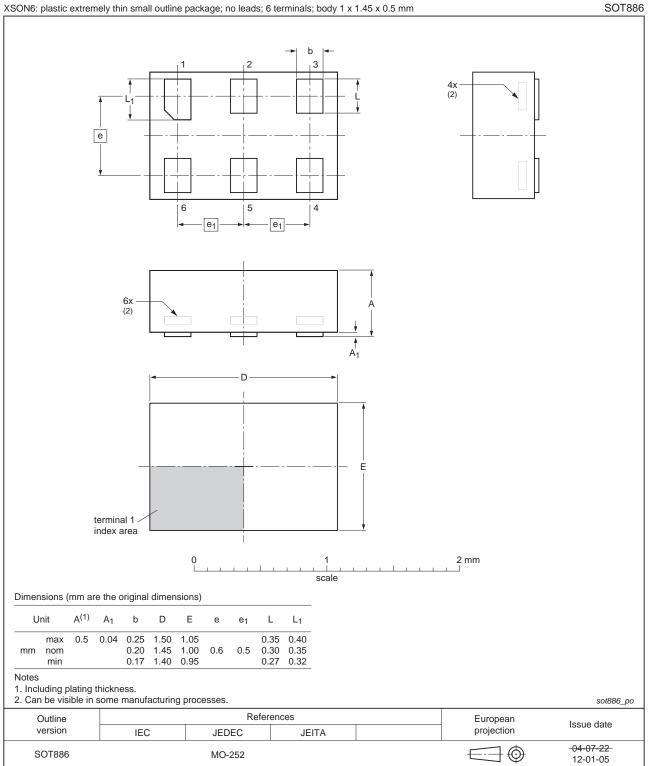
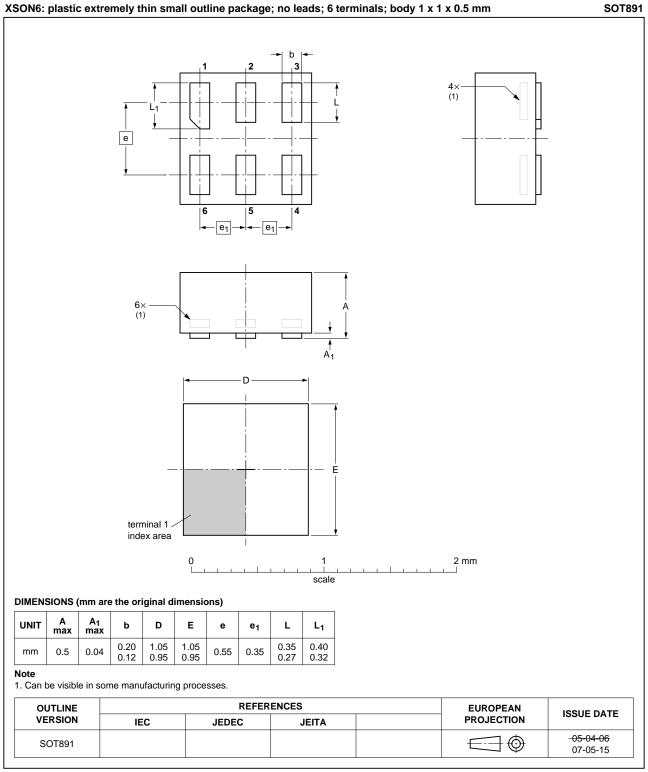


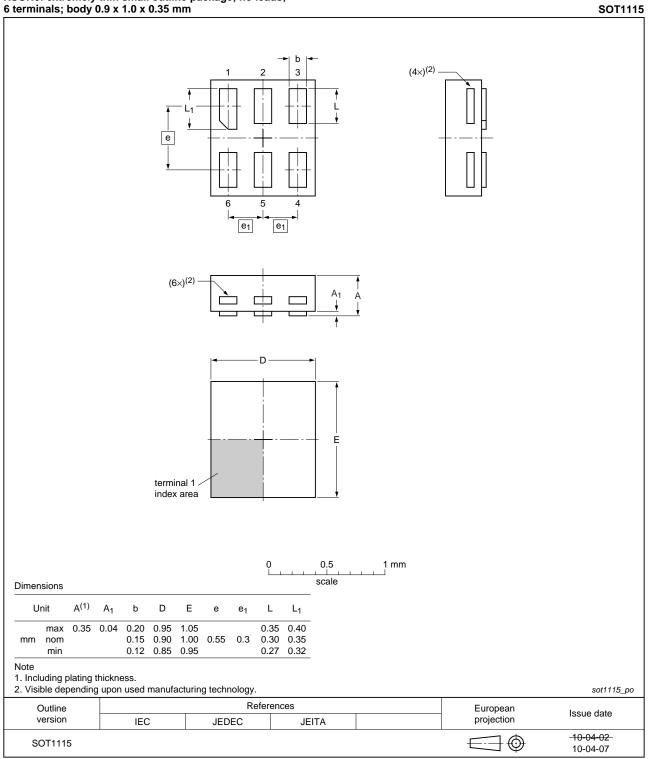
Fig 12. Package outline SOT886 (XSON6)

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XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

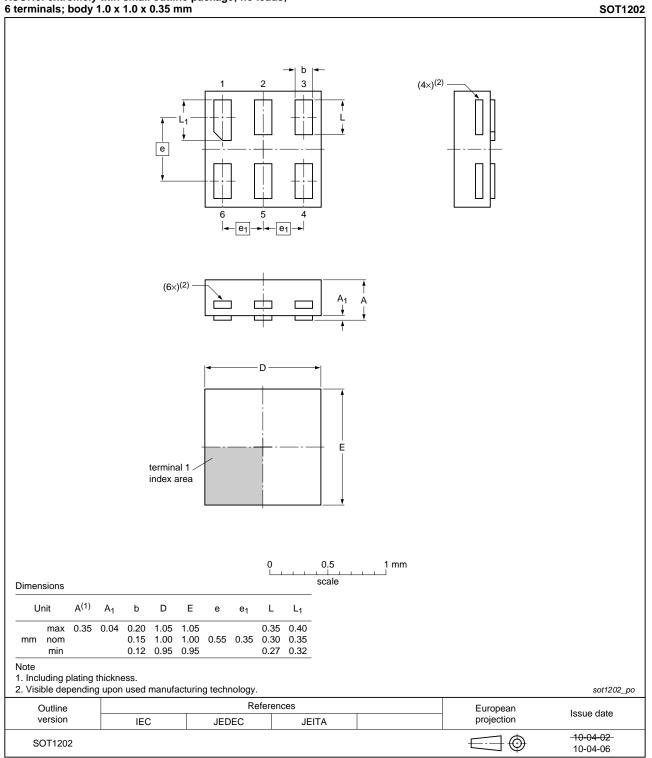
Fig 13. Package outline SOT891 (XSON6)



XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

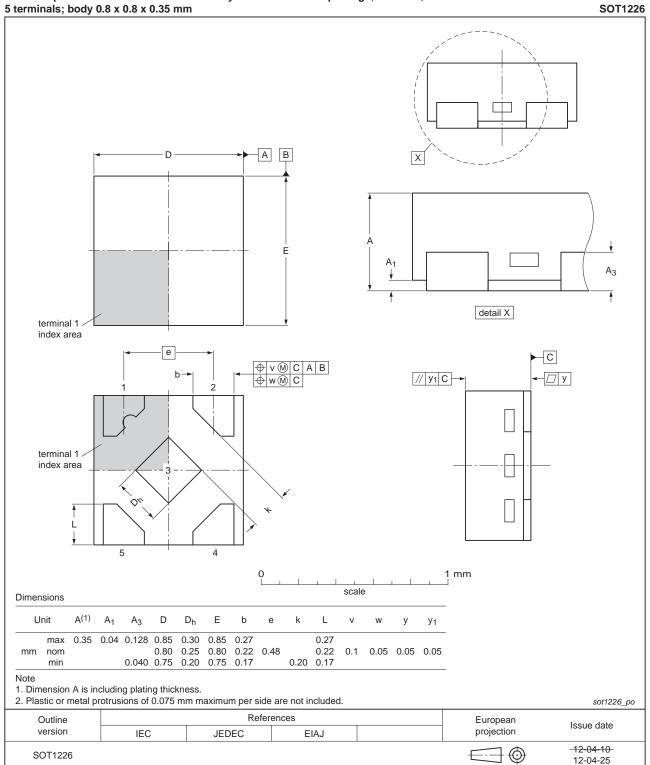
Fig 14. Package outline SOT1115 (XSON6)

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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1202 (XSON6)



X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm

Fig 16. Package outline SOT1226 (X2SON5)

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14. Abbreviations

Table 11. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

15. Revision history

Table 12.	Revision h	nistory

	-			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G00 v.10	20120702	Product data sheet	-	74LVC1G00 v.9
Modifications:	 Added type 	number 74LVC1G00GX (S	OT1226)	
	 Package or 	utline drawing of SOT886 (F	igure 12) modified.	
74LVC1G00 v.9	20111207	Product data sheet	-	74LVC1G00 v.8
Modifications:	 Legal pages 	s updated.		
74LVC1G00 v.8	20101020	Product data sheet	-	74LVC1G00 v.7
74LVC1G00 v.7	20070717	Product data sheet	-	74LVC1G00 v.6
74LVC1G00 v.6	20060915	Product data sheet	-	74LVC1G00 v.5
74LVC1G00 v.5	20040907	Product specification	-	74LVC1G00 v.4
74LVC1G00 v.4	20021115	Product specification	-	74LVC1G00 v.3
74LVC1G00 v.3	20020515	Product specification	-	74LVC1G00 v.2
74LVC1G00 v.2	20010405	Product specification	-	74LVC1G00 v.1
74LVC1G00 v.1	20001108	Product specification	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Single 2-input NAND gate

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